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Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Active
Core Processor	ARM® Cortex®-A9
Number of Cores/Bus Width	4 Core, 32-Bit
Speed	800MHz
Co-Processors/DSP	Multimedia; NEON™ SIMD
RAM Controllers	LPDDR2, DDR3L, DDR3
Graphics Acceleration	Yes
Display & Interface Controllers	HDMI, Keypad, LCD, LVDS, MIPI/DSI, Parallel
Ethernet	10/100/1000Mbps (1)
SATA	SATA 3Gbps (1)
USB	USB 2.0 + PHY (3), USB 2.0 OTG + PHY (1)
Voltage - I/O	1.8V, 2.5V, 2.8V, 3.3V
Operating Temperature	-40°C ~ 105°C (TA)
Security Features	ARM TZ, A-HAB, CAAM, CSU, SJC, SNVS
Package / Case	624-FBGA, FCBGA
Supplier Device Package	624-FCBGA (21x21)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx6qp7cvt8ab

The i.MX 6DualPlus/6QuadPlus processors offers numerous advanced features, such as:

- **Multilevel memory system**—The multilevel memory system of each processor is based on the L1 instruction and data caches, L2 cache, and internal and external memory. The processors support many types of external memory devices, including DDR3, DDR3L, LPDDR2, NOR Flash, PSRAM, cellular RAM, NAND Flash (MLC and SLC), OneNAND™, and managed NAND, including eMMC up to rev 4.4/4.41.
- **Smart speed technology**—The processors have power management throughout the device that enables the rich suite of multimedia features and peripherals to consume minimum power in both active and various low power modes. Smart speed technology enables the designer to deliver a feature-rich product, requiring levels of power far lower than industry expectations.
- **Dynamic voltage and frequency scaling**—The processors improve the power efficiency of devices by scaling the voltage and frequency to optimize performance.
- **Multimedia powerhouse**—The multimedia performance of each processor is enhanced by a multilevel cache system, Neon® MPE (Media Processor Engine) co-processor, a multi-standard hardware video codec, 2 autonomous and independent image processing units (IPU), and a programmable smart DMA (SDMA) controller.
- **Powerful graphics acceleration**—Each processor provides three independent, integrated graphics processing units: an OpenGL® ES 3.0 3D graphics accelerator with four shaders (up to 198 MTri/s and OpenCL support), 2D graphics accelerator, and dedicated OpenVG™ 1.1 accelerator.
- **Interface flexibility**—Each processor supports connections to a variety of interfaces: LCD controller for up to four displays (including parallel display, HDMI1.4, MIPI display, and LVDS display), dual CMOS sensor interface (parallel or through MIPI), high-speed USB on-the-go with PHY, high-speed USB host with PHY, multiple expansion card ports (high-speed MMC/SDIO host and other), 10/100/1000 Mbps Gigabit Ethernet controller, and a variety of other popular interfaces (such as UART, I²C, and I²S serial audio, SATA-II, and PCIe-II).
- **Advanced security**—The processors deliver hardware-enabled security features that enable secure e-commerce, digital rights management (DRM), information encryption, secure boot, and secure software downloads. The security features are discussed in detail in the i.MX 6Dual/6Quad security reference manual (IMX6DQ6SDLSRM).
- **Integrated power management**—The processors integrate linear regulators and internally generate voltage levels for different domains. This significantly simplifies system power management structure.

1.1 Ordering Information

Table 1 shows examples of orderable part numbers covered by this data sheet. This table does not include all possible orderable part numbers. The latest part numbers are available on nxp.com/imx6series. If your desired part number is not listed in the table, or you have questions about available parts, see nxp.com/imx6series or contact your NXP representative.

Table 1. Example Orderable Part Numbers

Part Number	Quad/Dual	CPU Options	Speed ¹	Temperature Grade	Package
MCIMX6DP7CVT8AA	i.MX 6DualPlus	VPU, GPU	800 MHz	Industrial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (lidded)
MCIMX6DP7CVT8AB	i.MX 6DualPlus	VPU, GPU	800 MHz	Industrial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (lidded)
MCIMX6QP7CVT8AA	i.MX 6QuadPlus	VPU, GPU	800 MHz	Industrial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (lidded)
MCIMX6QP7CVT8AB	i.MX 6QuadPlus	VPU, GPU	800 MHz	Industrial	21 mm x 21 mm, 0.8 mm pitch, FCPBGA (lidded)

¹ For 800 MHz speed grade: If a 24 MHz input clock is used (required for USB), the maximum speed is limited to 792 MHz.

Figure 1 describes the part number nomenclature to identify the characteristics of the specific part number you have (for example, cores, frequency, temperature grade, fuse options, silicon revision). Figure 1 applies to the i.MX 6DualPlus/6QuadPlus.

The two characteristics that identify which data sheet a specific part applies to are the part number series field and the temperature grade (junction) field:

- The i.MX 6DualPlus/6QuadPlus Automotive Applications Processors data sheet (IMX6DQPAEC) covers parts listed for the “Plus” series and with “A” indicating automotive temperature.
- The i.MX 6DualPlus/6QuadPlus Applications Processors for Consumer Products data sheet (IMX6DQPCEC) covers parts listed with “D (Commercial temp)” or “E (Extended Commercial temp)”
- The i.MX 6DualPlus/6QuadPlus Applications Processors for Industrial Products data sheet (IMX6DQPIEC) covers parts listed with “C (Industrial temp)”

Ensure that you have the right data sheet for your specific part by checking the fields: Part # Series (DP/QP), temperature grade (junction) (A), and Frequency (8).

4.9.3.1 EIM Interface Pads Allocation

EIM supports 32-bit, 16-bit and 8-bit devices operating in address/data separate or multiplexed modes. Table 36 provides EIM interface pads allocation in different modes.

Table 36. EIM Internal Module Multiplexing¹

Setup	Non Multiplexed Address/Data Mode							Multiplexed Address/Data mode	
	8 Bit				16 Bit		32 Bit	16 Bit	32 Bit
	MUM = 0, DSZ = 100	MUM = 0, DSZ = 101	MUM = 0, DSZ = 110	MUM = 0, DSZ = 111	MUM = 0, DSZ = 001	MUM = 0, DSZ = 010	MUM = 0, DSZ = 011	MUM = 1, DSZ = 001	MUM = 1, DSZ = 011
EIM_ADDR [15:00]	EIM_AD [15:00]	EIM_AD [15:00]	EIM_AD [15:00]	EIM_AD [15:00]	EIM_AD [15:00]	EIM_AD [15:00]	EIM_AD [15:00]	EIM_AD [15:00]	EIM_AD [15:00]
EIM_ADDR [25:16]	EIM_ADDR [25:16]	EIM_ADDR [25:16]	EIM_ADDR [25:16]	EIM_ADDR [25:16]	EIM_ADDR [25:16]	EIM_ADDR [25:16]	EIM_ADDR [25:16]	EIM_ADDR [25:16]	EIM_DATA [09:00]
EIM_DATA [07:00], EIM_EB0_B	EIM_DATA [07:00]	—	—	—	EIM_DATA [07:00]	—	EIM_DATA [07:00]	EIM_AD [07:00]	EIM_AD [07:00]
EIM_DATA [15:08], EIM_EB1_B	—	EIM_DATA [15:08]	—	—	EIM_DATA [15:08]	—	EIM_DATA [15:08]	EIM_AD [15:08]	EIM_AD [15:08]
EIM_DATA [23:16], EIM_EB2_B	—	—	EIM_DATA [23:16]	—	—	EIM_DATA [23:16]	EIM_DATA [23:16]	—	EIM_DATA [07:00]
EIM_DATA [31:24], EIM_EB3_B	—	—	—	EIM_DATA [31:24]	—	EIM_DATA [31:24]	EIM_DATA [31:24]	—	EIM_DATA [15:08]

¹ For more information on configuration ports mentioned in this table, see the i.MX 6DualPlus/6QuadPlus reference manual (IMX6DQPRM).

Figure 12 to Figure 15 provide few examples of basic EIM accesses to external memory devices with the timing parameters mentioned previously for specific control parameters settings.

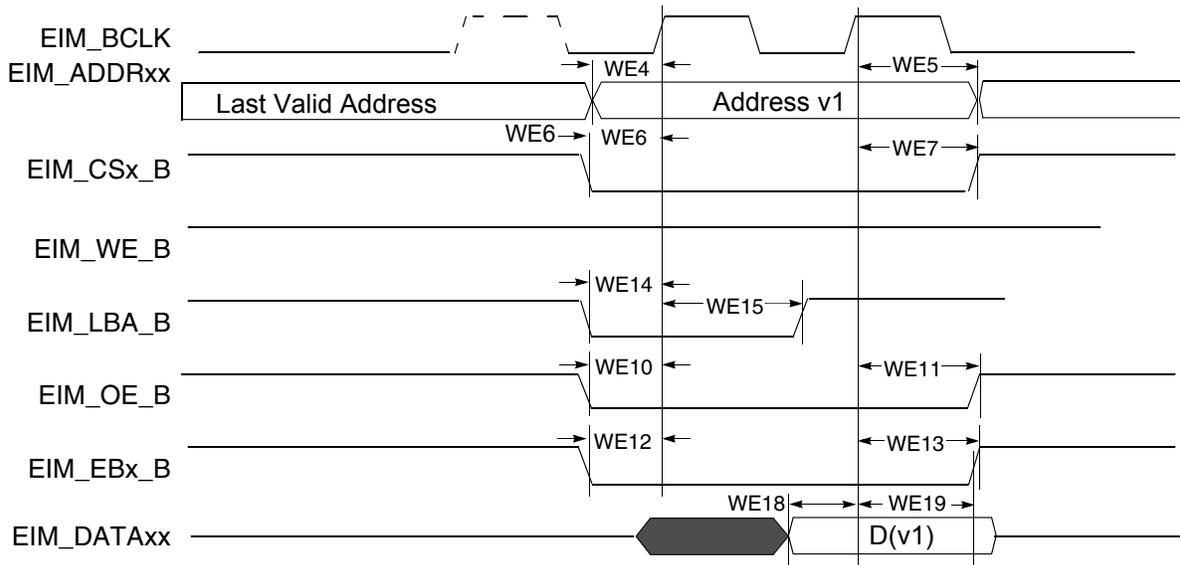


Figure 12. Synchronous Memory Read Access, WSC=1

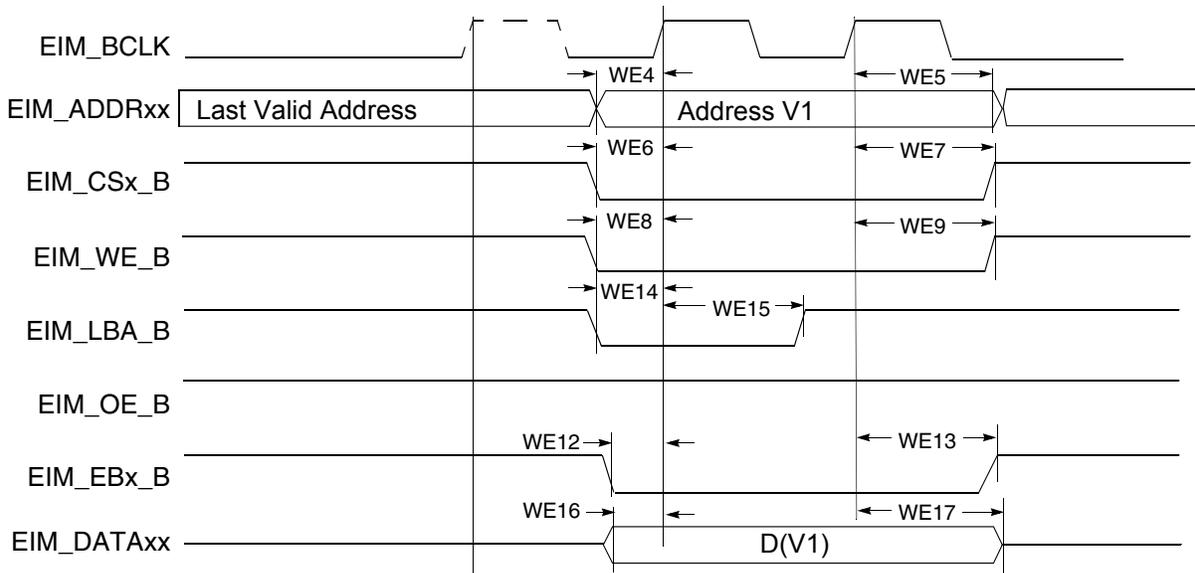


Figure 13. Synchronous Memory, Write Access, WSC=1, WBEA=0 and WADV=0

Electrical Characteristics

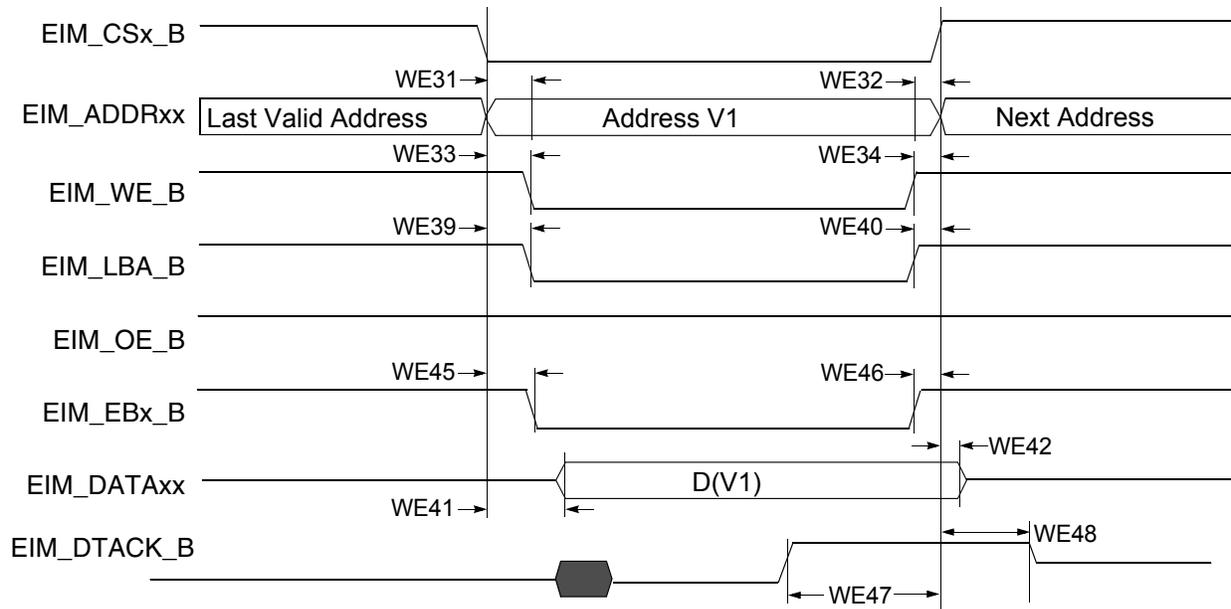


Figure 21. DTACK Mode Write Access (DAP=0)

Table 38. EIM Asynchronous Timing Parameters Relative to Chip Select^{1, 2}

Ref No.	Parameter	Determination by Synchronous measured parameters	Min	Max	Unit
WE31	EIM_CSx_B valid to Address Valid	WE4-WE6-CSA×t	-3.5-CSA×t	3.5-CSA×t	ns
WE32	Address Invalid to EIM_CSx_B Invalid	WE7-WE5-CSN×t	-3.5-CSN×t	3.5-CSN×t	ns
WE32A (muxed A/D)	EIM_CSx_B valid to Address Invalid	t+WE4-WE7+(ADVN+ADVA+1-CSA)×t	t-3.5+(ADVN+ADVA+1-CSA)×t	t+3.5+(ADVN+ADVA+1-CSA)×t	ns
WE33	EIM_CSx_B Valid to EIM_WE_B Valid	WE8-WE6+(WEA-WCSA)×t	-3.5+(WEA-WCSA)×t	3.5+(WEA-WCSA)×t	ns
WE34	EIM_WE_B Invalid to EIM_CSx_B Invalid	WE7-WE9+(WEN-WCSN)×t	-3.5+(WEN-WCSN)×t	3.5+(WEN-WCSN)×t	ns
WE35	EIM_CSx_B Valid to EIM_OE_B Valid	WE10-WE6+(OEA-RCSA)×t	-3.5+(OEA-RCSA)×t	3.5+(OEA-RCSA)×t	ns
WE35A (muxed A/D)	EIM_CSx_B Valid to EIM_OE_B Valid	WE10-WE6+(OEA+RADVN+RADVA+ADH+1-RCSA)×t	-3.5+(OEA+RADVN+RADVA+ADH+1-RCSA)×t	3.5+(OEA+RADVN+RADVA+ADH+1-RCSA)×t	ns
WE36	EIM_OE_B Invalid to EIM_CSx_B Invalid	WE7-WE11+(OEN-RCSN)×t	-3.5+(OEN-RCSN)×t	3.5+(OEN-RCSN)×t	ns
WE37	EIM_CSx_B Valid to EIM_EBx_B Valid (Read access)	WE12-WE6+(RBEA-RCSA)×t	-3.5+(RBEA-RCSA)×t	3.5+(RBEA-RCSA)×t	ns
WE38	EIM_EBx_B Invalid to EIM_CSx_B Invalid (Read access)	WE7-WE13+(RBEN-RCSN)×t	-3.5+(RBEN-RCSN)×t	3.5+(RBEN-RCSN)×t	ns
WE39	EIM_CSx_B Valid to EIM_LBA_B Valid	WE14-WE6+(ADVA-CSA)×t	-3.5+(ADVA-CSA)×t	3.5+(ADVA-CSA)×t	ns

4.11.1 Asynchronous Mode AC Timing (ONFI 1.0 Compatible)

Asynchronous mode AC timings are provided as multiplications of the clock cycle and fixed delay. The Maximum I/O speed of GPMI in Asynchronous mode is about 50 MB/s. Figure 22 through Figure 25 depict the relative timing between GPMI signals at the module level for different operations under Asynchronous mode. Table 40 describes the timing parameters (NF1–NF17) that are shown in the figures.

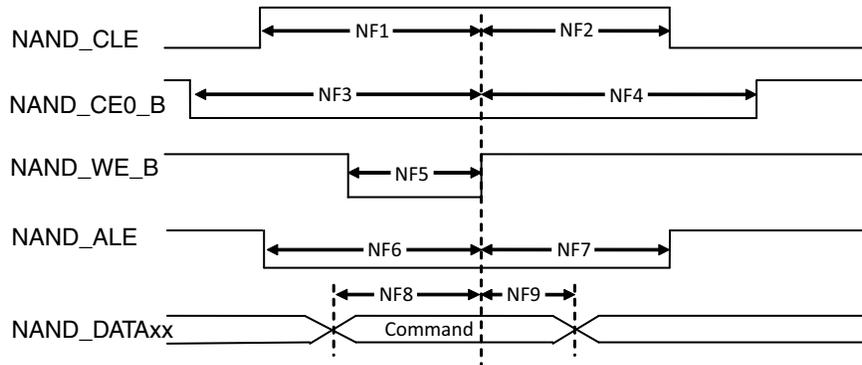


Figure 22. Command Latch Cycle Timing Diagram

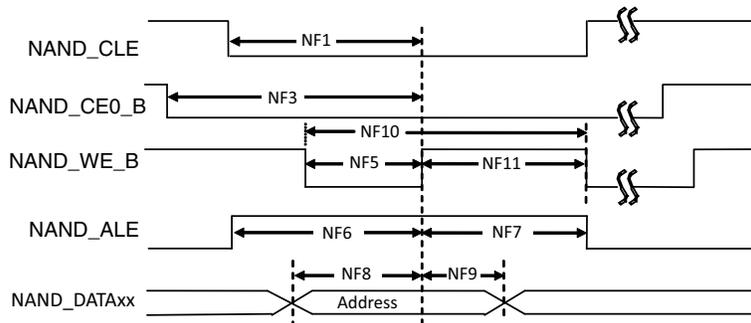


Figure 23. Address Latch Cycle Timing Diagram

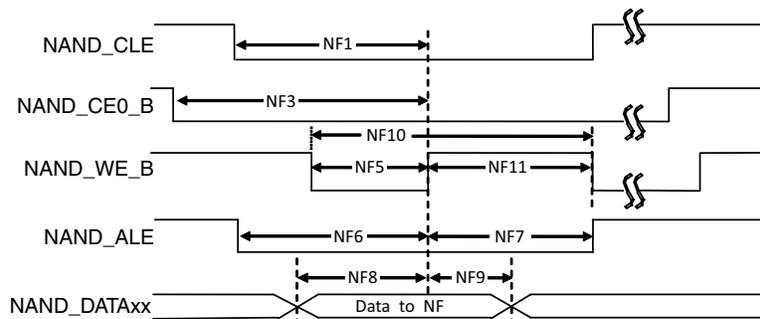


Figure 24. Write Data Latch Cycle Timing Diagram

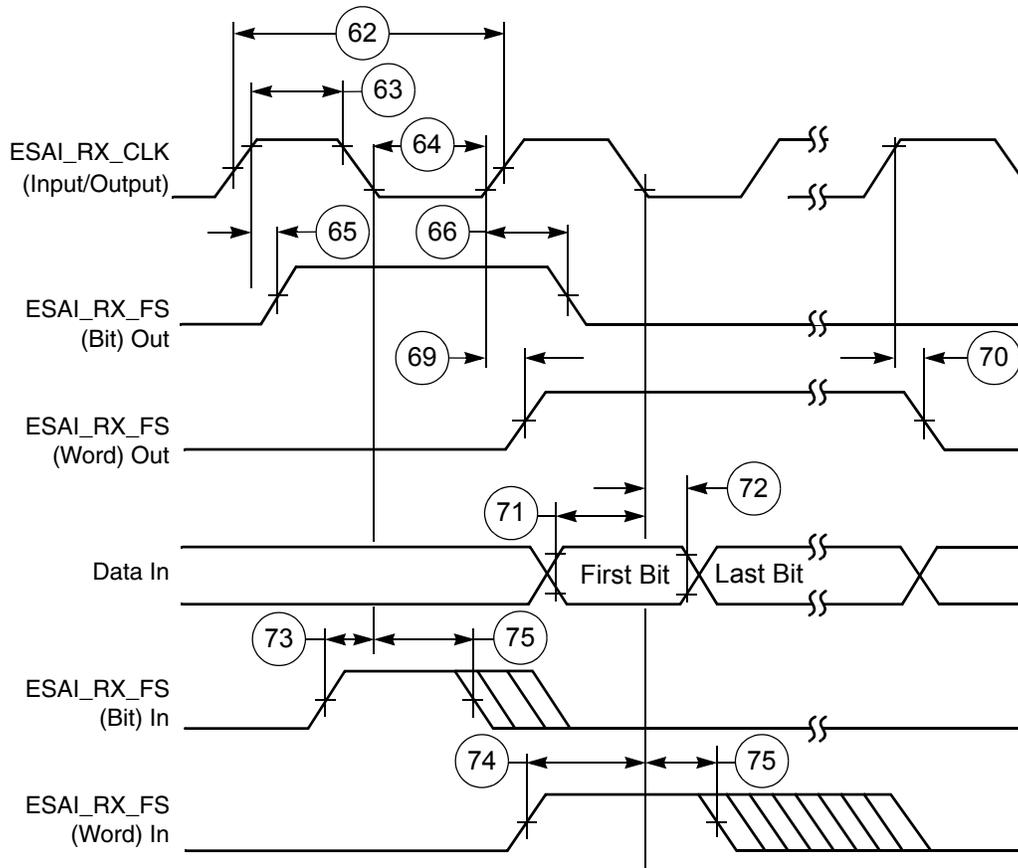


Figure 36. ESAI Receiver Timing

Electrical Characteristics

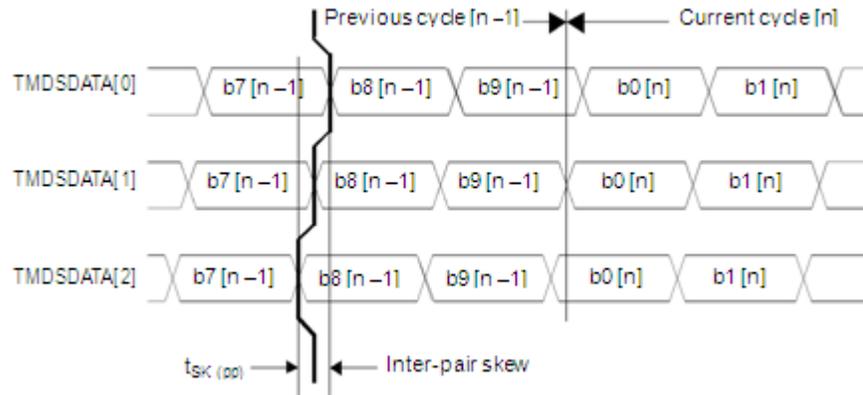


Figure 54. Inter-Pair Skew Definition

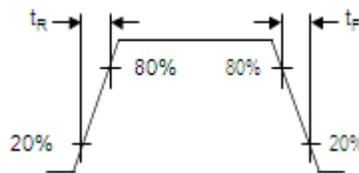


Figure 55. TMDs Output Signals Rise and Fall Time Definition

Table 56. Switching Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
TMDs Drivers Specifications						
—	Maximum serial data rate	—	—	—	3.4	Gbps
F_{TMDsCLK}	TMDsCLK frequency	On TMDsCLKP/N outputs	25	—	340	MHz
P_{TMDsCLK}	TMDsCLK period	$RL = 50 \Omega$ See Figure 51.	2.94	—	40	ns
t_{CDC}	TMDsCLK duty cycle	$t_{\text{CDC}} = t_{\text{CPH}} / P_{\text{TMDsCLK}}$ $RL = 50 \Omega$ See Figure 51.	40	50	60	%
t_{CPH}	TMDsCLK high time	$RL = 50 \Omega$ See Figure 51.	4	5	6	UI
t_{CPL}	TMDsCLK low time	$RL = 50 \Omega$ See Figure 51.	4	5	6	UI
—	TMDsCLK jitter ¹	$RL = 50 \Omega$	—	—	0.25	UI
$t_{\text{SK}(p)}$	Intra-pair (pulse) skew	$RL = 50 \Omega$ See Figure 53.	—	—	0.15	UI
$t_{\text{SK}(pp)}$	Inter-pair skew	$RL = 50 \Omega$ See Figure 54.	—	—	1	UI
t_{R}	Differential output signal rise time	20–80% $RL = 50 \Omega$ See Figure 55.	75	—	0.4 UI	ps

4.12.10.1 IPU Sensor Interface Signal Mapping

The IPU supports a number of sensor input formats. Table 58 defines the mapping of the Sensor Interface Pins used for various supported interface formats.

Table 58. Camera Input Signal Cross Reference, Format, and Bits Per Cycle

Signal Name ¹	RGB565 8 bits 2 cycles	RGB565 ² 8 bits 3 cycles	RGB666 ³ 8 bits 3 cycles	RGB888 8 bits 3 cycles	YCbCr ⁴ 8 bits 2 cycles	RGB565 ⁵ 16 bits 1 cycle	YCbCr ⁶ 16 bits 1 cycle	YCbCr ⁷ 16 bits 1 cycle	YCbCr ⁸ 20 bits 1 cycle
IPUx_CSIx_ DATA00	—	—	—	—	—	—	—	0	C[0]
IPUx_CSIx_ DATA01	—	—	—	—	—	—	—	0	C[1]
IPUx_CSIx_ DATA02	—	—	—	—	—	—	—	C[0]	C[2]
IPUx_CSIx_ DATA03	—	—	—	—	—	—	—	C[1]	C[3]
IPUx_CSIx_ DATA04	—	—	—	—	—	B[0]	C[0]	C[2]	C[4]
IPU2_CSIx_ DATA_05	—	—	—	—	—	B[1]	C[1]	C[3]	C[5]
IPUx_CSIx_ DATA06	—	—	—	—	—	B[2]	C[2]	C[4]	C[6]
IPUx_CSIx_ DATA07	—	—	—	—	—	B[3]	C[3]	C[5]	C[7]
IPUx_CSIx_ DATA08	—	—	—	—	—	B[4]	C[4]	C[6]	C[8]
IPUx_CSIx_ DATA09	—	—	—	—	—	G[0]	C[5]	C[7]	C[9]
IPUx_CSIx_ DATA10	—	—	—	—	—	G[1]	C[6]	0	Y[0]
IPUx_CSIx_ DATA11	—	—	—	—	—	G[2]	C[7]	0	Y[1]
IPUx_CSIx_ DATA12	B[0], G[3]	R[2],G[4],B[2]	R/G/B[4]	R/G/B[0]	Y/C[0]	G[3]	Y[0]	Y[0]	Y[2]
IPUx_CSIx_ DATA13	B[1], G[4]	R[3],G[5],B[3]	R/G/B[5]	R/G/B[1]	Y/C[1]	G[4]	Y[1]	Y[1]	Y[3]
IPUx_CSIx_ DATA14	B[2], G[5]	R[4],G[0],B[4]	R/G/B[0]	R/G/B[2]	Y/C[2]	G[5]	Y[2]	Y[2]	Y[4]
IPUx_CSIx_ DATA15	B[3], R[0]	R[0],G[1],B[0]	R/G/B[1]	R/G/B[3]	Y/C[3]	R[0]	Y[3]	Y[3]	Y[5]
IPUx_CSIx_ DATA16	B[4], R[1]	R[1],G[2],B[1]	R/G/B[2]	R/G/B[4]	Y/C[4]	R[1]	Y[4]	Y[4]	Y[6]
IPUx_CSIx_ DATA17	G[0], R[2]	R[2],G[3],B[2]	R/G/B[3]	R/G/B[5]	Y/C[5]	R[2]	Y[5]	Y[5]	Y[7]
IPUx_CSIx_ DATA18	G[1], R[3]	R[3],G[4],B[3]	R/G/B[4]	R/G/B[6]	Y/C[6]	R[3]	Y[6]	Y[6]	Y[8]
IPUx_CSIx_ DATA19	G[2], R[4]	R[4],G[5],B[4]	R/G/B[5]	R/G/B[7]	Y/C[7]	R[4]	Y[7]	Y[7]	Y[9]

¹ IPU2_CSIx stands for IPU2_CSI1 or IPU2_CSI2.

There are special physical outputs to provide synchronous controls:

- The `ipp_disp_clk` is a dedicated base synchronous signal that is used to generate a base display (component, pixel) clock for a display.
- The `ipp_pin_1`–`ipp_pin_7` are general purpose synchronous pins, that can be used to provide HSYNC, VSYNC, DRDY or any else independent signal to a display.

The IPU has a system of internal binding counters for internal events (such as, HSYNC/VSYNC) calculation. The internal event (local start point) is synchronized with internal `DI_CLK`. A suitable control starts from the local start point with predefined UP and DOWN values to calculate control's changing points with half `DI_CLK` resolution. A full description of the counter system can be found in the IPU chapter of the i.MX 6DualPlus/6QuadPlus reference manual (IMX6DQPRM).

4.12.10.5.2 Asynchronous Controls

The asynchronous control is a data-oriented signal that changes its value with an output data according to additional internal flags coming with the data.

There are special physical outputs to provide asynchronous controls, as follows:

- The `ipp_d0_cs` and `ipp_d1_cs` pins are dedicated to provide chip select signals to two displays.
- The `ipp_pin_11`–`ipp_pin_17` are general purpose asynchronous pins, that can be used to provide WR, RD, RS or any other data-oriented signal to display.

NOTE

The IPU has independent signal generators for asynchronous signals toggling. When a DI decides to put a new asynchronous data on the bus, a new internal start (local start point) is generated. The signal generators calculate predefined UP and DOWN values to change pins states with half `DI_CLK` resolution.

4.12.10.6 Synchronous Interfaces to Standard Active Matrix TFT LCD Panels

4.12.10.6.1 IPU Display Operating Signals

The IPU uses four control signals and data to operate a standard synchronous interface:

- `IPP_DISP_CLK`—Clock to display
- `HSYNC`—Horizontal synchronization
- `VSYNC`—Vertical synchronization
- `DRDY`—Active data

All synchronous display controls are generated on the base of an internally generated “local start point”. The synchronous display controls can be placed on time axis with DI's offset, up and down parameters. The display access can be whole number of DI clock (`Tdick`) only. The `IPP_DATA` can not be moved relative to the local start point. The data bus of the synchronous interface is output direction only.

Electrical Characteristics

Table 61 shows timing characteristics of signals presented in Figure 61 and Figure 62.

Table 61. Synchronous Display Interface Timing Characteristics (Pixel Level)

ID	Parameter	Symbol	Value	Description	Unit
IP5	Display interface clock period	Tdicp	(see ¹)	Display interface clock IPP_DISP_CLK	ns
IP6	Display pixel clock period	Tdpcp	$DISP_CLK_PER_PIXEL \times Tdicp$	Time of translation of one pixel to display, DISP_CLK_PER_PIXEL—number of pixel components in one pixel (1..n). The DISP_CLK_PER_PIXEL is virtual parameter to define display pixel clock period. The DISP_CLK_PER_PIXEL is received by DC/DI one access division to n components.	ns
IP7	Screen width time	Tsw	$(SCREEN_WIDTH) \times Tdicp$	SCREEN_WIDTH—screen width in, interface clocks. horizontal blanking included. The SCREEN_WIDTH should be built by suitable DI's counter ² .	ns
IP8	HSYNC width time	Thsw	(HSYNC_WIDTH)	HSYNC_WIDTH—Hsync width in DI_CLK with 0.5 DI_CLK resolution. Defined by DI's counter.	ns
IP9	Horizontal blank interval 1	Thbi1	$BGXP \times Tdicp$	BGXP—width of a horizontal blanking before a first active data in a line (in interface clocks). The BGXP should be built by suitable DI's counter.	ns
IP10	Horizontal blank interval 2	Thbi2	$(SCREEN_WIDTH - BGXP - FW) \times Tdicp$	Width a horizontal blanking after a last active data in a line (in interface clocks) FW—width of active line in interface clocks. The FW should be built by suitable DI's counter.	ns
IP12	Screen height	Tsh	$(SCREEN_HEIGHT) \times Tsw$	SCREEN_HEIGHT— screen height in lines with blanking. The SCREEN_HEIGHT is a distance between 2 VSYNCs. The SCREEN_HEIGHT should be built by suitable DI's counter.	ns
IP13	VSYNC width	Tvsw	VSYNC_WIDTH	VSYNC_WIDTH—Vsync width in DI_CLK with 0.5 DI_CLK resolution. Defined by DI's counter.	ns
IP14	Vertical blank interval 1	Tvbi1	$BGYP \times Tsw$	BGYP—width of first Vertical blanking interval in line. The BGYP should be built by suitable DI's counter.	ns
IP15	Vertical blank interval 2	Tvbi2	$(SCREEN_HEIGHT - BGYP - FH) \times Tsw$	Width of second vertical blanking interval in line. The FH should be built by suitable DI's counter.	ns

Table 61. Synchronous Display Interface Timing Characteristics (Pixel Level) (continued)

ID	Parameter	Symbol	Value	Description	Unit
IP5o	Offset of IPP_DISP_CLK	Todicp	DISP_CLK_OFFSET × Tdiclk	DISP_CLK_OFFSET—offset of IPP_DISP_CLK edges from local start point, in DI_CLK×2 (0.5 DI_CLK Resolution). Defined by DISP_CLK counter.	ns
IP13o	Offset of VSYNC	Tovs	VSYNC_OFFSET × Tdiclk	VSYNC_OFFSET—offset of Vsync edges from a local start point, when a Vsync should be active, in DI_CLK×2 (0.5 DI_CLK Resolution). The VSYNC_OFFSET should be built by suitable DI's counter.	ns
IP8o	Offset of HSYNC	Tohs	HSYNC_OFFSET × Tdiclk	HSYNC_OFFSET—offset of Hsync edges from a local start point, when a Hsync should be active, in DI_CLK×2 (0.5 DI_CLK Resolution). The HSYNC_OFFSET should be built by suitable DI's counter.	ns
IP9o	Offset of DRDY	Todrdy	DRDY_OFFSET × Tdiclk	DRDY_OFFSET—offset of DRDY edges from a suitable local start point, when a corresponding data has been set on the bus, in DI_CLK×2 (0.5 DI_CLK Resolution). The DRDY_OFFSET should be built by suitable DI's counter.	ns

¹ Display interface clock period immediate value.

$$T_{dicp} = \begin{cases} T_{diclk} \times \frac{DISP_CLK_PERIOD}{DI_CLK_PERIOD}, & \text{for integer } \frac{DISP_CLK_PERIOD}{DI_CLK_PERIOD} \\ T_{diclk} \left(\text{floor} \left[\frac{DISP_CLK_PERIOD}{DI_CLK_PERIOD} \right] + 0.5 \pm 0.5 \right), & \text{for fractional } \frac{DISP_CLK_PERIOD}{DI_CLK_PERIOD} \end{cases}$$

DISP_CLK_PERIOD—number of DI_CLK per one Tdicp. Resolution 1/16 of DI_CLK.

DI_CLK_PERIOD—relation of between programing clock frequency and current system clock frequency

Display interface clock period average value.

$$\bar{T}_{dicp} = T_{diclk} \times \frac{DISP_CLK_PERIOD}{DI_CLK_PERIOD}$$

² DI's counter can define offset, period and UP/DOWN characteristic of output signal according to programed parameters of the counter. Same of parameters in the table are not defined by DI's registers directly (by name), but can be generated by corresponding DI's counter. The SCREEN_WIDTH is an input value for DI's HSYNC generation counter. The distance between HSYNCs is a SCREEN_WIDTH.

The maximum accuracy of UP/DOWN edge of controls is:

$$\text{Accuracy} = (0.5 \times T_{diclk}) \pm 0.62\text{ns}$$

The maximum accuracy of UP/DOWN edge of IPP_DISP_DATA is:

$$\text{Accuracy} = T_{diclk} \pm 0.62\text{ns}$$

The DISP_CLK_PERIOD, DI_CLK_PERIOD parameters are register-controlled.

4.12.16 SATA PHY Parameters

This section describes SATA PHY electrical specifications.

4.12.16.1 Transmitter and Receiver Characteristics

The SATA PHY meets or exceeds the electrical compliance requirements defined in the SATA specifications.

NOTE

The tables in the following sections indicate any exceptions to the SATA specification or aspects of the SATA PHY that exceed the standard, as well as provide information about parameters not defined in the standard.

The following subsections provide values obtained from a combination of simulations and silicon characterization.

4.12.16.1.1 SATA PHY Transmitter Characteristics

Table 68 provides specifications for SATA PHY transmitter characteristics.

Table 68. SATA PHY Transmitter Characteristics

Parameters	Symbol	Min	Typ	Max	Unit
Transmit common mode voltage	V_{CTM}	0.4	—	0.6	V
Transmitter pre-emphasis accuracy (measured change in de-emphasized bit)	—	-0.5	—	0.5	dB

4.12.16.1.2 SATA PHY Receiver Characteristics

Table 69 provides specifications for SATA PHY receiver characteristics.

Table 69. SATA PHY Receiver Characteristics

Parameters	Symbol	Min	Typ	Max	Unit
Minimum Rx eye height (differential peak-to-peak)	$V_{MIN_RX_EYE_HEIGHT}$	175	—	—	mV
Tolerance	PPM	-400	—	400	ppm

4.12.16.2 SATA_REXT Reference Resistor Connection

The impedance calibration process requires connection of reference resistor 191 Ω 1% precision resistor on SATA_REXT pad to ground.

Resistor calibration consists of learning which state of the internal Resistor Calibration register causes an internal, digitally trimmed calibration resistor to best match the impedance applied to the SATA_REXT pin. The calibration register value is then supplied to all Tx and Rx termination resistors.

During the calibration process (for a few tens of microseconds), up to 0.3 mW can be dissipated in the external SATA_REXT resistor. At other times, no power is dissipated by the SATA_REXT resistor.

Table 70. JTAG Timing (continued)

ID	Parameter ^{1,2}	All Frequencies		Unit
		Min	Max	
SJ9	JTAG_TMS, JTAG_TDI data hold time	25	—	ns
SJ10	JTAG_TCK low to JTAG_TDO data valid	—	44	ns
SJ11	JTAG_TCK low to JTAG_TDO high impedance	—	44	ns
SJ12	JTAG_TRST_B assert time	100	—	ns
SJ13	JTAG_TRST_B set-up time to JTAG_TCK low	40	—	ns

¹ T_{DC} = target frequency of SJC

² V_M = mid-point voltage

4.12.18 SPDIF Timing Parameters

The Sony/Philips Digital Interconnect Format (SPDIF) data is sent using the bi-phase marking code. When encoding, the SPDIF data signal is modulated by a clock that is twice the bit rate of the data signal.

Table 71 and Figure 84 and Figure 85 show SPDIF timing parameters for the Sony/Philips Digital Interconnect Format (SPDIF), including the timing of the modulating Rx clock (SPDIF_SR_CLK) for SPDIF in Rx mode and the timing of the modulating Tx clock (SPDIF_ST_CLK) for SPDIF in Tx mode.

Table 71. SPDIF Timing Parameters

Parameter	Symbol	Timing Parameter Range		Unit
		Min	Max	
SPDIF_IN Skew: asynchronous inputs, no specs apply	—	—	0.7	ns
SPDIF_OUT output (Load = 50pf)	—	—	1.5	ns
• Skew	—	—	24.2	
• Transition rising	—	—	31.3	
• Transition falling	—	—	31.3	
SPDIF_OUT output (Load = 30pf)	—	—	1.5	ns
• Skew	—	—	13.6	
• Transition rising	—	—	18.0	
• Transition falling	—	—	18.0	
Modulating Rx clock (SPDIF_SR_CLK) period	srckp	40.0	—	ns
SPDIF_SR_CLK high period	srckph	16.0	—	ns
SPDIF_SR_CLK low period	srckpl	16.0	—	ns
Modulating Tx clock (SPDIF_ST_CLK) period	stckp	40.0	—	ns
SPDIF_ST_CLK high period	stckph	16.0	—	ns
SPDIF_ST_CLK low period	stckpl	16.0	—	ns

4.12.19.2 SSI Receiver Timing with Internal Clock

Figure 87 depicts the SSI receiver internal clock timing and Table 74 lists the timing parameters for the receiver timing with the internal clock.

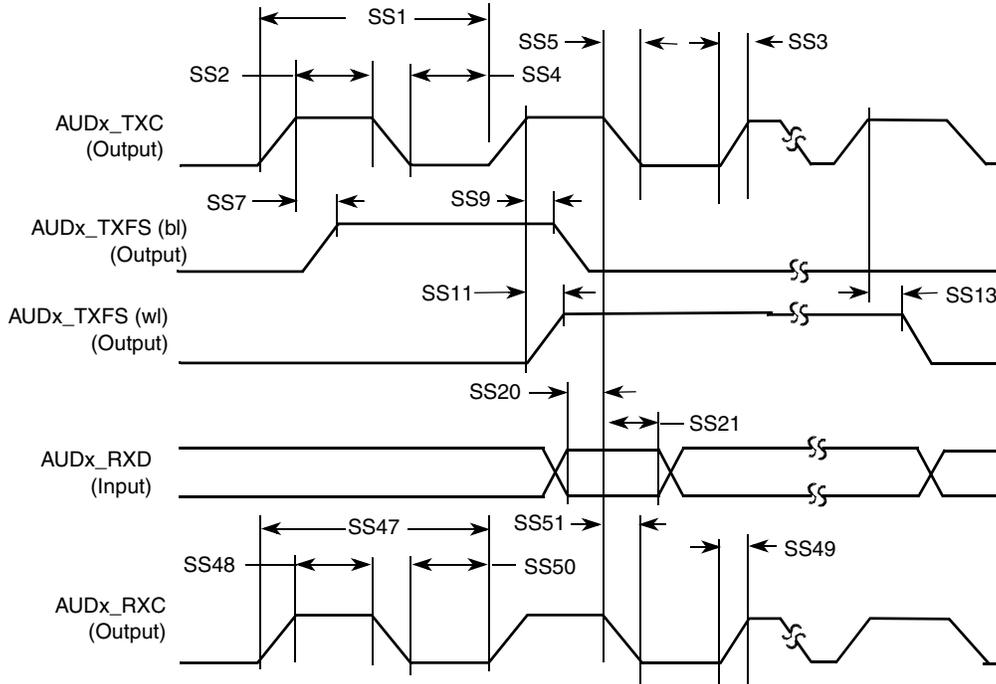


Figure 87. SSI Receiver Internal Clock Timing Diagram

Table 74. SSI Receiver Timing with Internal Clock

ID	Parameter	Min	Max	Unit
Internal Clock Operation				
SS1	AUDx_TXC/AUDx_RXC clock period	81.4	—	ns
SS2	AUDx_TXC/AUDx_RXC clock high period	36.0	—	ns
SS3	AUDx_TXC/AUDx_RXC clock rise time	—	6.0	ns
SS4	AUDx_TXC/AUDx_RXC clock low period	36.0	—	ns
SS5	AUDx_TXC/AUDx_RXC clock fall time	—	6.0	ns
SS7	AUDx_RXC high to AUDx_TXFS (bl) high	—	15.0	ns
SS9	AUDx_RXC high to AUDx_TXFS (bl) low	—	15.0	ns
SS11	AUDx_RXC high to AUDx_TXFS (wl) high	—	15.0	ns
SS13	AUDx_RXC high to AUDx_TXFS (wl) low	—	15.0	ns
SS20	AUDx_RXD setup time before AUDx_RXC low	10.0	—	ns
SS21	AUDx_RXD hold time after AUDx_RXC low	0.0	—	ns

4.12.21 USB HSIC Timings

This section describes the electrical information of the USB HSIC port.

NOTE

HSIC is a DDR signal. The following timing specification is for both rising and falling edges.

4.12.21.1 Transmit Timing

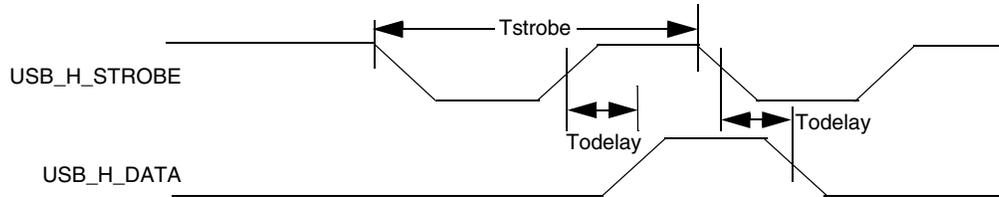


Figure 94. USB HSIC Transmit Waveform

Table 82. USB HSIC Transmit Parameters

Name	Parameter	Min	Max	Unit	Comment
Tstrobe	strobe period	4.166	4.167	ns	—
Todelay	data output delay time	550	1350	ps	Measured at 50% point
Tslew	strobe/data rising/falling time	0.7	2	V/ns	Averaged from 30% – 70% points

4.12.21.2 Receive Timing

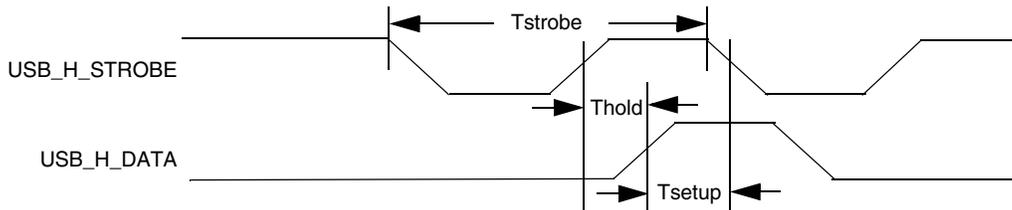


Figure 95. USB HSIC Receive Waveform

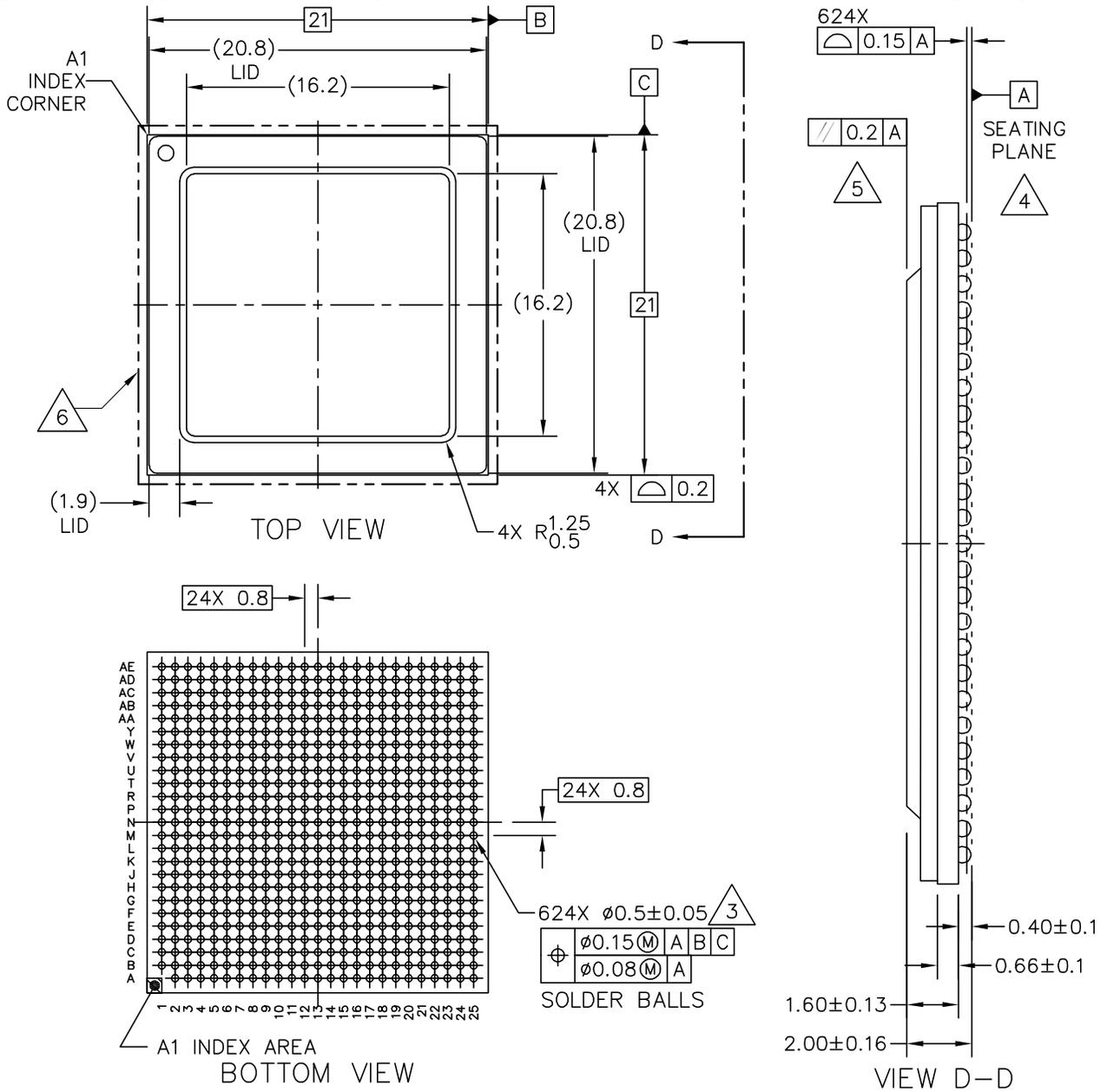
Table 83. USB HSIC Receive Parameters¹

Name	Parameter	Min	Max	Unit	Comment
Tstrobe	strobe period	4.166	4.167	ns	—
Thold	data hold time	300	—	ps	Measured at 50% point
Tsetup	data setup time	365	—	ps	Measured at 50% point
Tslew	strobe/data rising/falling time	0.7	2	V/ns	Averaged from 30% – 70% points

¹ The timings in the table are guaranteed when:
 —AC I/O voltage is between 0.9x to 1x of the I/O supply
 —DDR_SEL configuration bits of the I/O are set to (10)b

6.2.1.1 21 x 21 mm Lidded Package

Figure 96 and Figure 97 show the top, bottom, and side views of the 21 × 21 mm lidded package.



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TITLE: 624 I/O FC PBGA, 21 X 21 X 2 PKG, 0.8 MM PITCH, STAMPED LID	DOCUMENT NO: 98ASA00330D	REV: E
	STANDARD: NON-JEDEC	
	SOT1643-1	07 JAN 2016

Figure 96. 21 x 21 mm Lidded Package Top, Bottom, and Side Views (Sheet 1 of 2)

Table 86. 21 x 21 mm Supplies Contact Assignment (continued)

Supply Rail Name	Ball(s) Position(s)	Remark
VDDHIGH_CAP	H10, J10	Secondary supply for the 2.5 V domain (internal regulator output—requires capacitor if internal regulator is used)
VDDHIGH_IN	H9, J9	Primary supply for the 2.5 V regulator
VDDPU_CAP	H17, J17, K17, L17, M17, N17, P17	Secondary supply for the VPU and GPU (internal regulator output—requires capacitor if internal regulator is used)
VDDSOC_CAP	R10, T10, T13, T14, U10, U13, U14	Secondary supply for the SoC and PU (internal regulator output—requires capacitor if internal regulator is used)
VDDSOC_IN	H16, J16, K16, L16, M16, N16, P16, R16, T16, U16	Primary supply for the SoC and PU regulators
VDDUSB_CAP	F9	Secondary supply for the 3 V domain (internal regulator output—requires capacitor if internal regulator is used)
ZQPAD	AE17	Connect ZQPAD to an external 240Ω 1% resistor to GND. This is a reference used during DRAM output buffer driver calibration.

6.2.3 21 x 21 mm Functional Contact Assignments

Table 87 displays an alpha-sorted list of the signal assignments including power rails. The table also includes out of reset pad state.

Table 87. 21 x 21 mm Functional Contact Assignments

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition ¹			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value ²
BOOT_MODE0	C12	VDD_SNVS_IN	GPIO	ALT0	SRC_BOOT_MODE0	Input	PD (100K)
BOOT_MODE1	F12	VDD_SNVS_IN	GPIO	ALT0	SRC_BOOT_MODE1	Input	PD (100K)
CLK1_N	C7	VDD_HIGH_CAP	—	—	CLK1_N	—	—
CLK1_P	D7	VDD_HIGH_CAP	—	—	CLK1_P	—	—
CLK2_N	C5	VDD_HIGH_CAP	—	—	CLK2_N	—	—
CLK2_P	D5	VDD_HIGH_CAP	—	—	CLK2_P	—	—
CSI_CLK0M	F4	NVCC_MIPI	—	—	CSI_CLK_N	—	—
CSI_CLK0P	F3	NVCC_MIPI	—	—	CSI_CLK_P	—	—
CSI_D0M	E4	NVCC_MIPI	—	—	CSI_DATA0_N	—	—
CSI_D0P	E3	NVCC_MIPI	—	—	CSI_DATA0_P	—	—
CSI_D1M	D1	NVCC_MIPI	—	—	CSI_DATA1_N	—	—

Table 87. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition ¹			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value ²
DISP0_DAT14	U25	NVCC_LCD	GPIO	ALT5	GPIO5_IO08	Input	PU (100K)
DISP0_DAT15	T22	NVCC_LCD	GPIO	ALT5	GPIO5_IO09	Input	PU (100K)
DISP0_DAT16	T21	NVCC_LCD	GPIO	ALT5	GPIO5_IO10	Input	PU (100K)
DISP0_DAT17	U24	NVCC_LCD	GPIO	ALT5	GPIO5_IO11	Input	PU (100K)
DISP0_DAT18	V25	NVCC_LCD	GPIO	ALT5	GPIO5_IO12	Input	PU (100K)
DISP0_DAT19	U23	NVCC_LCD	GPIO	ALT5	GPIO5_IO13	Input	PU (100K)
DISP0_DAT2	P23	NVCC_LCD	GPIO	ALT5	GPIO4_IO23	Input	PU (100K)
DISP0_DAT20	U22	NVCC_LCD	GPIO	ALT5	GPIO5_IO14	Input	PU (100K)
DISP0_DAT21	T20	NVCC_LCD	GPIO	ALT5	GPIO5_IO15	Input	PU (100K)
DISP0_DAT22	V24	NVCC_LCD	GPIO	ALT5	GPIO5_IO16	Input	PU (100K)
DISP0_DAT23	W24	NVCC_LCD	GPIO	ALT5	GPIO5_IO17	Input	PU (100K)
DISP0_DAT3	P21	NVCC_LCD	GPIO	ALT5	GPIO4_IO24	Input	PU (100K)
DISP0_DAT4	P20	NVCC_LCD	GPIO	ALT5	GPIO4_IO25	Input	PU (100K)
DISP0_DAT5	R25	NVCC_LCD	GPIO	ALT5	GPIO4_IO26	Input	PU (100K)
DISP0_DAT6	R23	NVCC_LCD	GPIO	ALT5	GPIO4_IO27	Input	PU (100K)
DISP0_DAT7	R24	NVCC_LCD	GPIO	ALT5	GPIO4_IO28	Input	PU (100K)
DISP0_DAT8	R22	NVCC_LCD	GPIO	ALT5	GPIO4_IO29	Input	PU (100K)
DISP0_DAT9	T25	NVCC_LCD	GPIO	ALT5	GPIO4_IO30	Input	PU (100K)
DRAM_A0	AC14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR00	Output	0
DRAM_A1	AB14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR01	Output	0
DRAM_A10	AA15	NVCC_DRAM	DDR	ALT0	DRAM_ADDR10	Output	0
DRAM_A11	AC12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR11	Output	0
DRAM_A12	AD12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR12	Output	0
DRAM_A13	AC17	NVCC_DRAM	DDR	ALT0	DRAM_ADDR13	Output	0
DRAM_A14	AA12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR14	Output	0
DRAM_A15	Y12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR15	Output	0
DRAM_A2	AA14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR02	Output	0
DRAM_A3	Y14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR03	Output	0
DRAM_A4	W14	NVCC_DRAM	DDR	ALT0	DRAM_ADDR04	Output	0
DRAM_A5	AE13	NVCC_DRAM	DDR	ALT0	DRAM_ADDR05	Output	0
DRAM_A6	AC13	NVCC_DRAM	DDR	ALT0	DRAM_ADDR06	Output	0
DRAM_A7	Y13	NVCC_DRAM	DDR	ALT0	DRAM_ADDR07	Output	0
DRAM_A8	AB13	NVCC_DRAM	DDR	ALT0	DRAM_ADDR08	Output	0
DRAM_A9	AE12	NVCC_DRAM	DDR	ALT0	DRAM_ADDR09	Output	0
DRAM_CAS	AE16	NVCC_DRAM	DDR	ALT0	DRAM_CAS_B	Output	0
DRAM_CS0	Y16	NVCC_DRAM	DDR	ALT0	DRAM_CS0_B	Output	0

Table 87. 21 x 21 mm Functional Contact Assignments (continued)

Ball Name	Ball	Power Group	Ball Type	Out of Reset Condition ¹			
				Default Mode (Reset Mode)	Default Function (Signal Name)	Input/Output	Value ²
LVDS0_TX1_P	U3	NVCC_LVDS_2P5	LVDS	ALT0	LVDS0_TX1_P	Input	Keeper
LVDS0_TX2_N	V2	NVCC_LVDS_2P5	LVDS	—	LVDS0_TX2_N	—	—
LVDS0_TX2_P	V1	NVCC_LVDS_2P5	LVDS	ALT0	LVDS0_TX2_P	Input	Keeper
LVDS0_TX3_N	W2	NVCC_LVDS_2P5	LVDS	—	LVDS0_TX3_N	—	—
LVDS0_TX3_P	W1	NVCC_LVDS_2P5	LVDS	ALT0	LVDS0_TX3_P	Input	Keeper
LVDS1_CLK_N	Y3	NVCC_LVDS_2P5	LVDS	—	LVDS1_CLK_N	—	—
LVDS1_CLK_P	Y4	NVCC_LVDS_2P5	LVDS	ALT0	LVDS1_CLK_P	Input	Keeper
LVDS1_TX0_N	Y1	NVCC_LVDS_2P5	LVDS	—	LVDS1_TX0_N	—	—
LVDS1_TX0_P	Y2	NVCC_LVDS_2P5	LVDS	ALT0	LVDS1_TX0_P	Input	Keeper
LVDS1_TX1_N	AA2	NVCC_LVDS_2P5	LVDS	—	LVDS1_TX1_N	—	—
LVDS1_TX1_P	AA1	NVCC_LVDS_2P5	LVDS	ALT0	LVDS1_TX1_P	Input	Keeper
LVDS1_TX2_N	AB1	NVCC_LVDS_2P5	LVDS	—	LVDS1_TX2_N	—	—
LVDS1_TX2_P	AB2	NVCC_LVDS_2P5	LVDS	ALT0	LVDS1_TX2_P	Input	Keeper
LVDS1_TX3_N	AA3	NVCC_LVDS_2P5	LVDS	—	LVDS1_TX3_N	—	—
LVDS1_TX3_P	AA4	NVCC_LVDS_2P5	LVDS	ALT0	LVDS1_TX3_P	Input	Keeper
NANDF_ALE	A16	NVCC_NANDF	GPIO	ALT5	GPIO6_IO08	Input	PU (100K)
NANDF_CLE	C15	NVCC_NANDF	GPIO	ALT5	GPIO6_IO07	Input	PU (100K)
NANDF_CS0	F15	NVCC_NANDF	GPIO	ALT5	GPIO6_IO11	Input	PU (100K)
NANDF_CS1	C16	NVCC_NANDF	GPIO	ALT5	GPIO6_IO14	Input	PU (100K)
NANDF_CS2	A17	NVCC_NANDF	GPIO	ALT5	GPIO6_IO15	Input	PU (100K)
NANDF_CS3	D16	NVCC_NANDF	GPIO	ALT5	GPIO6_IO16	Input	PU (100K)
NANDF_D0	A18	NVCC_NANDF	GPIO	ALT5	GPIO2_IO00	Input	PU (100K)
NANDF_D1	C17	NVCC_NANDF	GPIO	ALT5	GPIO2_IO01	Input	PU (100K)
NANDF_D2	F16	NVCC_NANDF	GPIO	ALT5	GPIO2_IO02	Input	PU (100K)
NANDF_D3	D17	NVCC_NANDF	GPIO	ALT5	GPIO2_IO03	Input	PU (100K)
NANDF_D4	A19	NVCC_NANDF	GPIO	ALT5	GPIO2_IO04	Input	PU (100K)
NANDF_D5	B18	NVCC_NANDF	GPIO	ALT5	GPIO2_IO05	Input	PU (100K)
NANDF_D6	E17	NVCC_NANDF	GPIO	ALT5	GPIO2_IO06	Input	PU (100K)
NANDF_D7	C18	NVCC_NANDF	GPIO	ALT5	GPIO2_IO07	Input	PU (100K)
NANDF_RB0	B16	NVCC_NANDF	GPIO	ALT5	GPIO6_IO10	Input	PU (100K)
NANDF_WP_B	E15	NVCC_NANDF	GPIO	ALT5	GPIO6_IO09	Input	PU (100K)
ONOFF	D12	VDD_SNVS_IN	GPIO	—	SRC_ONOFF	Input	PU (100K)
PCIE_RXM	B1	PCIE_VPH	—	—	PCIE_RX_N	—	—
PCIE_RXP	B2	PCIE_VPH	—	—	PCIE_RX_P	—	—
PCIE_TXM	A3	PCIE_VPH	—	—	PCIE_TX_N	—	—
PCIE_TXP	B3	PCIE_VPH	—	—	PCIE_TX_P	—	—